

Supporting Information

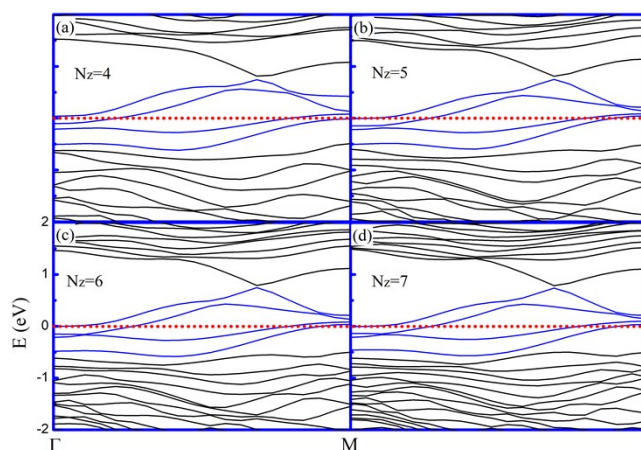


Figure S1. Calculated band structure for the zigzag MoSSe nanoribbons as a function of its width as measured by the N_z parameter. (a) $N_z=4$, (b) $N_z=5$, (c) $N_z=6$, (d) $N_z=7$. The horizontal dotted red line marks the Fermi level, set as energy reference (0 eV).

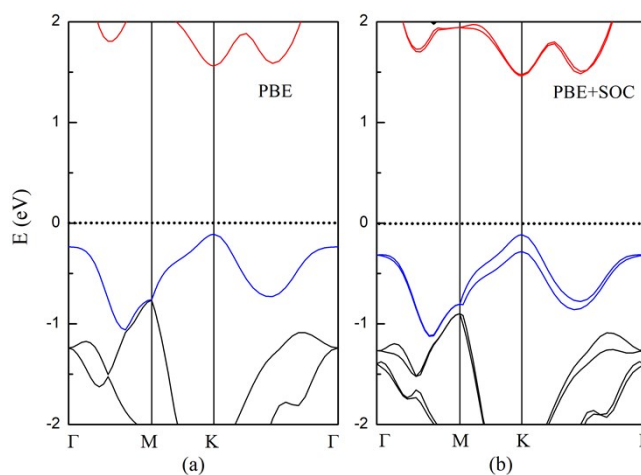


Figure S2. Calculated band structure of the two-dimensional MoSSe sheet at the (a) PBE and (b) PBE+SOC level. The horizontal black dotted line marks the Fermi level, set at 0 eV.

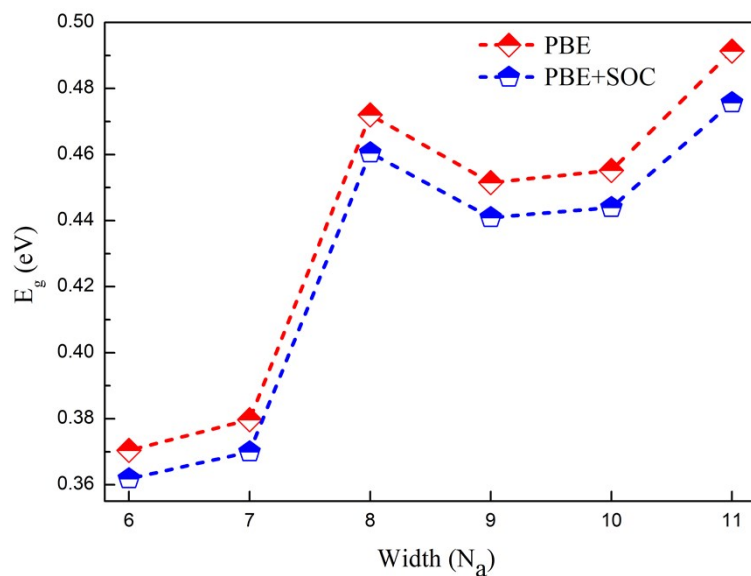


Figure S3. Calculated band gap for the armchair MoSSe nanoribbons as a function of its width as denoted by the N_a parameter in the 6 to 11 range. The red dotted line has been calculated at the PBE level, and the blue dotted line at the PBE+SOC level.

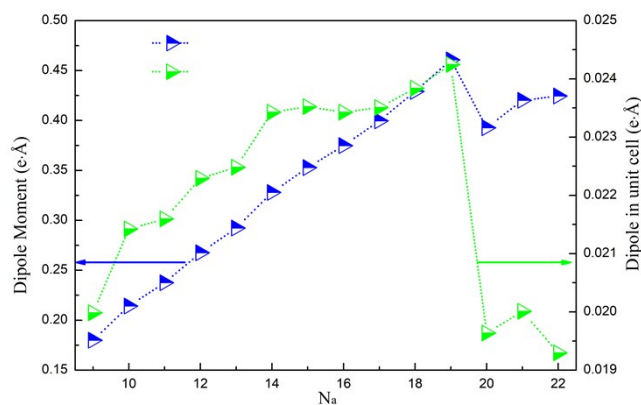


Figure S4. Calculated dipole moment for the zigzag MoSSe nanoribbons as a function of its width as measured by the N_a parameter in the 9 to 22 range. The right vertical axis reports the dipole moment per unit cell of the nanoribbon.

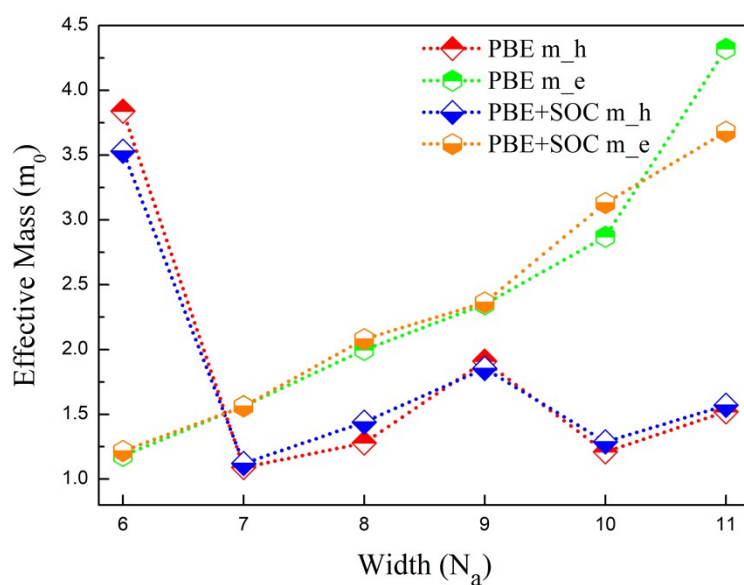


Figure S5. Calculated effective mass of electron and hole for the armchair MoSSe nanoribbons as a function of its width as measured by the N_a parameter. The red and green dotted traces report the PBE hole and electron mass, respectively. The blue and orange dotted traces show the PBE+SOC hole and electron mass, respectively.

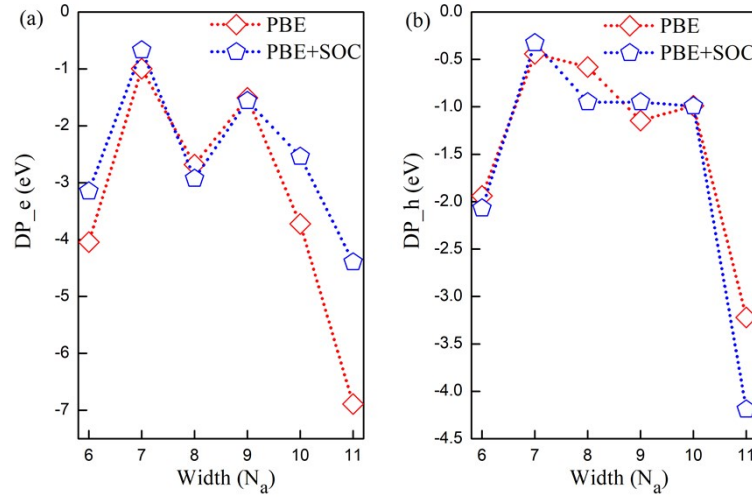


Figure S6. Calculated deformation potential (DP) of (a) electron and (b) hole for the armchair MoSSe nanoribbons as a function of its width as measured by the N_a parameter. Red and blue symbols report the PBE and PBE+SOC results, respectively.

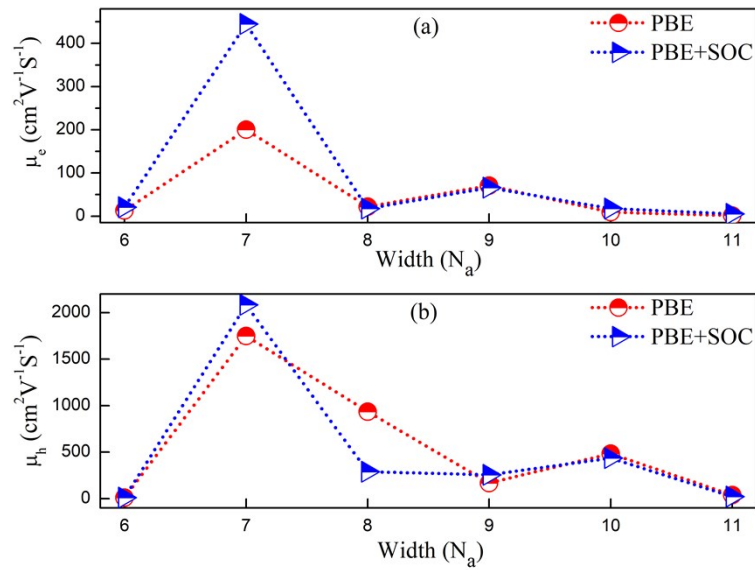


Figure S7. Calculated carrier mobility of (a) electron and (b) hole for the armchair MoSSe nanoribbons as a function of its width as measured by the N_a parameter. Red and blue symbols report the PBE and PBE+SOC results, respectively.